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1. Global joint venture starts operations as WeEn Semiconductors

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Product data sheet

1. General description

AC Thyristor Triac power switch in a SOT226A (I2PAK) plastic package with self-protective clamping capabilities against low and high energy transients.

2. Features and benefits

- Clamping structure ensuring safe high over-voltage withstand capability
- Direct interfacing with low power drivers and microcontrollers
- Full cycle AC conduction
- Over-voltage withstand capability to IEC 61000-4-5
- Pin compatible with standard triacs
- Planar passivated for voltage ruggedness and reliability
- Protective self turn-on capability for high energy transients
- Safe clamping capability for low energy over-voltage transients
- Sensitive gate for easy logic level triggering
- · Triggering in three quadrants only
- Very high immunity to false turn-on by dV/dt

3. Applications

- AC fan, pump and compressor controls
- Highly inductive, resistive and safety loads
- Large and small appliances (White Goods)
- Reversing induction motor controls

4. Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------------|--|---|-----|-----|-----|------|
| V_{DRM} | repetitive peak off- state voltage | | - | - | 800 | V |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 20 \text{ ms}$; Fig. 4; Fig. 5 | - | - | 51 | Α |
| T _j | junction temperature | | - | - | 125 | °C |
| I _{T(RMS)} | RMS on-state current | full sine wave; $T_{mb} \le 108$ °C; Fig. 1; Fig. 2; Fig. 3 | - | - | 6 | Α |
| V _{PP} | peak pulse voltage | T_j = 25 °C; non-repetitive, off-state; Fig. 6 | - | - | 2 | kV |





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| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---------------------------------------|--|-----|-----|-----|------|
| Static char | acteristics | | | | | |
| I _{GT} | gate trigger current | V_D = 12 V; I_T = 100 mA; LD+ G+; T_j = 25 °C; Fig. 8 | - | - | 10 | mA |
| | | V_D = 12 V; I_T = 100 mA; LD+ G-; T_j = 25 °C; <u>Fig. 8</u> | - | - | 10 | mA |
| | | $V_D = 12 \text{ V; } I_T = 100 \text{ mA; LD- G-;}$ $T_j = 25 \text{ °C; } Fig. 8$ | - | - | 10 | mA |
| V _{CL} | clamping voltage | I _{CL} = 0.1 mA; t _p = 1 ms; T _j = 25 °C | 850 | - | - | V |
| Dynamic cl | naracteristics | | l | | | J |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 536 V; T_j = 125 °C; (V_{DM} = 67% of V_{DRM}); exponential waveform; gate open circuit; Fig. 13 | 500 | - | - | V/µs |
| dl _{com} /dt | rate of change of commutating current | V_D = 400 V; T_j = 125 °C; $I_{T(RMS)}$ = 6 A; dV_{com}/dt = 1 V/ μ s; gate open circuit; Fig. 14; Fig. 15 | 10 | - | - | A/ms |

5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|---------------------|--------------------|----------------|
| 1 | СМ | common | | LD |
| 2 | LD | load | | G |
| 3 | G | gate | | G— CM |
| mb | LD | mounting base; load | | 003aaf296 |
| | | | I2PAK (SOT226A) | |

6. Ordering information

Table 3. Ordering information

| Type number | Package | | | | | |
|-------------|---------|--|---------|--|--|--|
| | Name | Description | Version | | | |
| ACTT6G-800E | I2PAK | plastic single-ended package (I2PAK); TO-262 | SOT226A | | | |

AC Thyristor Triac power switch

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------|--------------------------------------|---|-----|-----|------------------|
| V_{DRM} | repetitive peak off-state voltage | | - | 800 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; $T_{mb} \le 108 \text{ °C}$; Fig. 1; Fig. 2; Fig. 3 | - | 6 | Α |
| I _{TSM} | non-repetitive peak on-state current | full sine wave; $T_{j(init)} = 25 ^{\circ}\text{C}$; $t_p = 16.7 \text{ms}$ | - | 56 | A |
| | | full sine wave; $T_{j(init)}$ = 25 °C; t_p = 20 ms; Fig. 4; Fig. 5 | - | 51 | Α |
| I ² t | I ² t for fusing | t _p = 10 ms; sine-wave pulse | - | 13 | A ² s |
| dl _T /dt | rate of rise of on-state current | $I_T = 9 \text{ A}; I_G = 0.2 \text{ A}; dI_G/dt = 0.2 \text{ A/µs}$ | - | 100 | A/µs |
| I _{GM} | peak gate current | t = 20 μs | - | 2 | Α |
| P _{GM} | peak gate power | | - | 5 | W |
| P _{G(AV)} | average gate power | over any 20 ms period | - | 0.5 | W |
| T _{stg} | storage temperature | | -40 | 150 | °C |
| T _j | junction temperature | | - | 125 | °C |
| V_{PP} | peak pulse voltage | T _j = 25 °C; non-repetitive, off-state; Fig. 6 | - | 2 | kV |

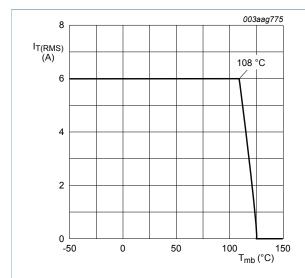


Fig. 1. RMS on-state current as a function of mounting base temperature; maximum values

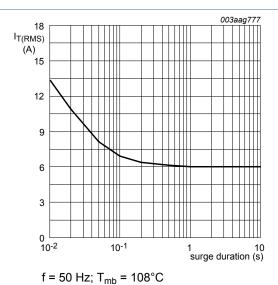


Fig. 2. RMS on-state current as a function of surge duration; maximum values

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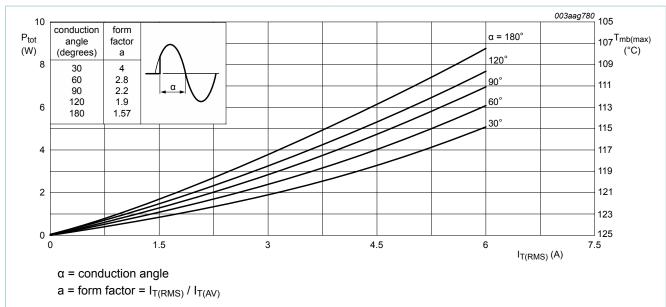


Fig. 3. Total power dissipation as a function of RMS on-state current; maximum values

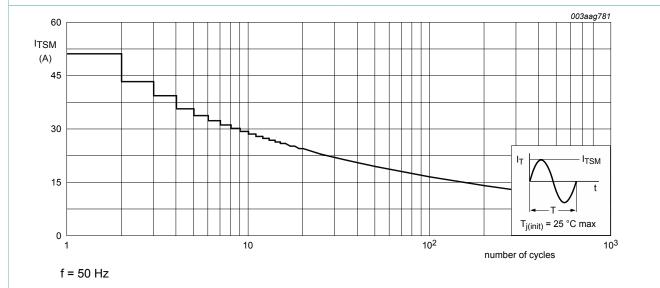


Fig. 4. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values

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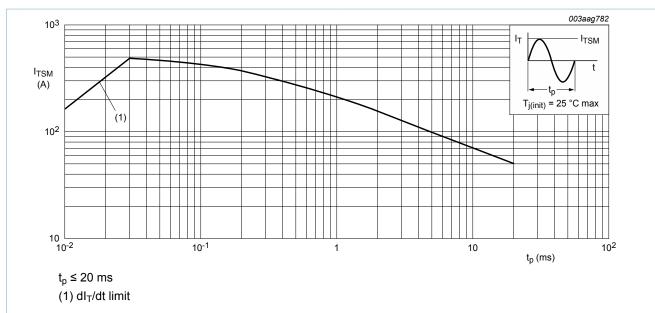


Fig. 5. Non-repetitive peak on-state current as a function of pulse width; maximum values

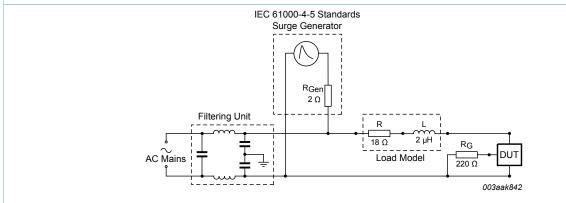


Fig. 6. Test circuit for inductive and resistive loads with conditions equivalent to IEC 61000-4-5

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Thermal characteristics

Table 5. **Thermal characteristics**

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---|--------------------|-----|-----|-----|------|
| R _{th(j-mb)} | thermal resistance from junction to mounting base | half cycle; Fig. 7 | - | - | 2.4 | K/W |
| | | full cycle; Fig. 7 | - | - | 2 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | - | 60 | - | K/W |

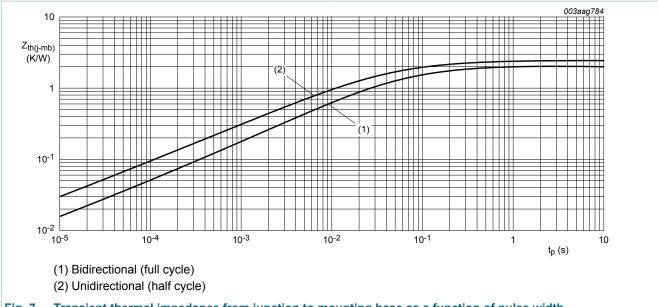


Fig. 7. Transient thermal impedance from junction to mounting base as a function of pulse width

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9. Characteristics

Table 6. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---------------------------------------|--|-----|------|-----|------|
| Static chara | acteristics | | · | | | |
| I_{GT} | gate trigger current | V_D = 12 V; I_T = 100 mA; LD+ G+; T_j = 25 °C; Fig. 8 | - | - | 10 | mA |
| | | $V_D = 12 \text{ V}; I_T = 100 \text{ mA}; LD+ G-;$ $T_j = 25 \text{ °C}; Fig. 8$ | - | - | 10 | mA |
| | | $V_D = 12 \text{ V; } I_T = 100 \text{ mA; LD- G-;}$ $T_j = 25 \text{ °C; } Fig. 8$ | - | - | 10 | mA |
| IL | latching current | $V_D = 12 \text{ V; } I_G = 100 \text{ mA; LD+ G+;}$ $T_j = 25 \text{ °C; } Fig. 9$ | - | - | 30 | mA |
| | | V_D = 12 V; I_G = 100 mA; LD+ G-; T_j = 25 °C; Fig. 9 | - | - | 40 | mA |
| | | V_D = 12 V; I_G = 100 mA; LD- G-; T_j = 25 °C; <u>Fig. 9</u> | - | - | 30 | mA |
| I _H | holding current | V _D = 12 V; T _j = 25 °C; <u>Fig. 10</u> | - | - | 25 | mA |
| V _T | on-state voltage | I _T = 8 A; T _j = 25 °C; <u>Fig. 11</u> | - | - | 1.7 | V |
| V _{GT} g | gate trigger voltage | $V_D = 12 \text{ V}; I_T = 100 \text{ mA}; T_j = 25 \text{ °C};$ Fig. 12 | - | 0.8 | 1 | V |
| | | V _D = 400 V; I _T = 100 mA; T _j = 125 °C; Fig. 12 | 0.2 | 0.45 | - | V |
| I _D | off-state current | V _D = 800 V; T _j = 25 °C | - | - | 10 | μA |
| | | V _D = 800 V; T _j = 125 °C | - | - | 0.5 | mA |
| V _{CL} | clamping voltage | I_{CL} = 0.1 mA; t_p = 1 ms; T_j = 25 °C | 850 | - | - | V |
| Dynamic cl | haracteristics | 1 | | | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 536 V; T_j = 125 °C; (V_{DM} = 67% of V_{DRM}); exponential waveform; gate open circuit; Fig. 13 | 500 | - | - | V/µs |
| dl _{com} /dt | rate of change of commutating current | V_D = 400 V; T_j = 125 °C; $I_{T(RMS)}$ = 6 A; dV_{com}/dt = 20 V/ μ s; (snubberless condition); gate open circuit; Fig. 14; Fig. 15 | 3.5 | - | - | A/ms |
| | | V_D = 400 V; T_j = 125 °C; $I_{T(RMS)}$ = 6 A; dV_{com}/dt = 10 V/ μ s; gate open circuit; Fig. 14; Fig. 15 | 5 | - | - | A/ms |
| | | V_D = 400 V; T_j = 125 °C; $I_{T(RMS)}$ = 6 A; dV_{com}/dt = 1 V/ μ s; gate open circuit; Fig. 14; Fig. 15 | 10 | - | - | A/ms |

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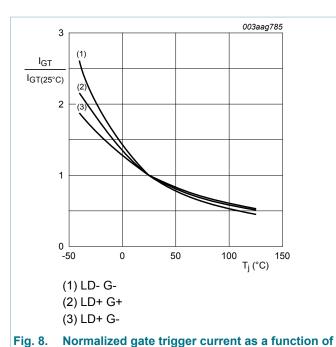
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ΙL

I_{L(25°C)}

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003aag786



T_j (°C) Fig. 9. Normalized latching current as a function of junction temperature

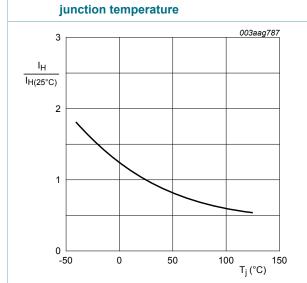
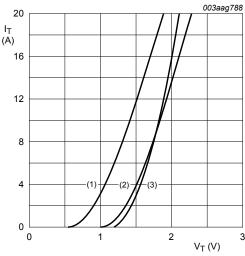


Fig. 10. Normalized holding current as a function of junction temperature



 $V_o = 1.109 \text{ V}; R_s = 0.076 \Omega$

(1) T_i = 125 °C; typical values

(2) T_i = 125 °C; maximum values

(3) T_i = 25 °C; maximum values

Fig. 11. On-state current as a function of on-state voltage

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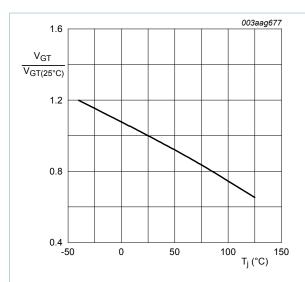
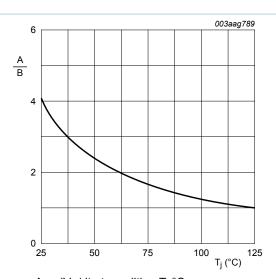
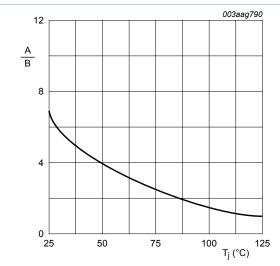


Fig. 12. Normalized gate trigger voltage as a function of junction temperature



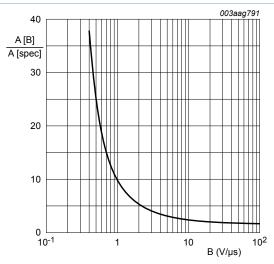
A = dV_D/dt at condition T_j °C B = dV_D/dt at condition T_i [125] °C

Fig. 13. Normalized rate of rise of off-state voltage as a function of junction temperature



A = dI_{com}/dt at condition T_j °C B = dI_{com}/dt at condition T_j [125] °C V_D = 400 V

Fig. 14. Normalized critical rate of rise of commutating current as a function of junction temperature



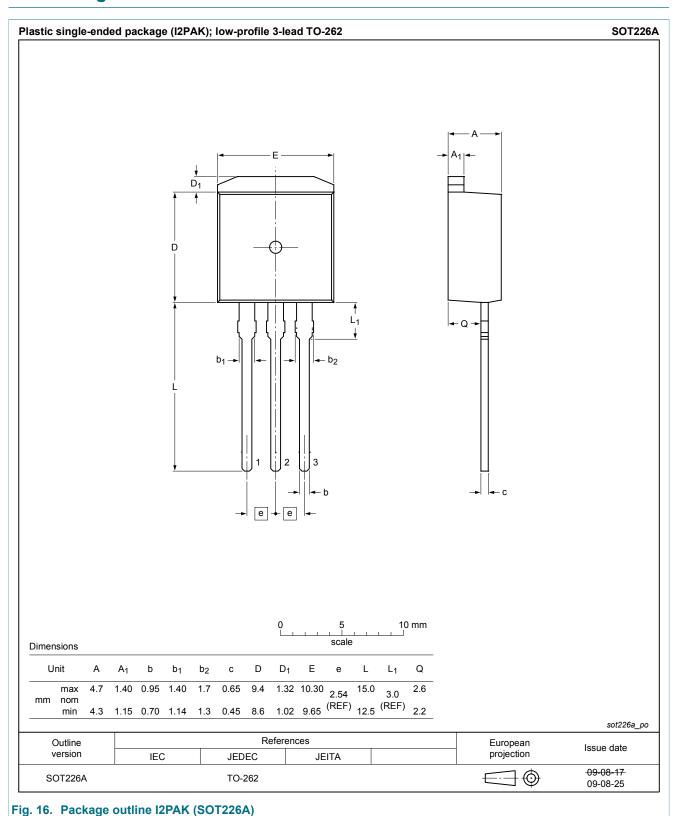
A [B] is dI_{com}/dt at condition B, dV_{com}/dt A [spec] is the specified data sheet value of dI_{com}/dt turn-off time < 20 ms

Fig. 15. Normalized critical rate of change of commutating current as a function of critical rate of change of commutating voltage; minimum values

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10. Package outline



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11. Legal information

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|--------------------------------------|--------------------|---|
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